Attorney Docket: BHT/3230-56

#### IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

**Applicant** 

YEH

Application No.

10/601,701

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June 24, 2003

Title

METHOD FOR FABRICATION OF POLYCRYSTALLIN

SILICON THIN FILM TRANSISTORS

**Group Art Unit** 

2812

Examiner

Unknown

Docket No.

BHT/3230-56

MAIL STOP
OFFICE OF INITIAL PATENT EXAMINATION

Honorable Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

### TRANSMITTAL COVER SHEET

Sir:

Transmitted herewith for filing are the following:

- 1. INFORMATION DISCLOSURE STATEMENT.
- 2. Form PTO-1449 (in duplicate), along with copies of nine (9) references cited therein.

The Commissioner is hereby authorized to charge any fees which may be required for the filing of this document to **Deposit Account No. 501874**.

Respectfully submitted,

Date: October 20, 2003

By:

Bruce H. Troxell Reg. No. 26,592

TROXELL LAW OFFICE PLLC 5205 Leesburg Pike, Suite 1404 Falls Church, Virginia 22041 Telephone: (703) 575-2711 Telefax: (703) 575-2707

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# MAIL STOP OFFICE OF INITIAL PATENT EXAMINATION

Honorable Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

## **INFORMATION DISCLOSURE STATEMENT**

Sir:

In compliance with the duty of disclosure under 37 CFR 1.56, and 37 CFR 1.97-1.98, the documents listed on the attached form PTO-1449 are hereby made of record in this patent application. Copies of the listed documents are enclosed.

As this Information Disclosure Statement is being filed prior to the mailing of the first Official Action in this application, no fee is believed due in order to have the enclosed references considered by the Examiner and made of record in the application.

Early action on the merits of the application is earnestly solicited.

Respectfully submitted,

Date: October 20, 2003

By: Bruco I

Bruce H. Troxell Reg. No. 26,592

TROXELL LAW OFFICE PLLC 5205 Leesburg Pike, Suite 1404 Falls Church, Virginia 22041 Telephone: (703) 575-2711 Telefax: (703) 575-2707

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FORM PTO 1449 (modified)			ATTY DOCKET NO. BHT/32	ATTY DOCKET NO. BHT/3230-56 APPLICATION NO. 10/601,701			
U.S. DEPARTMENT OF COMMERCE PATENT AND TRADEMARK OFFICE  LIST OF REFERENCES CITED BY APPLICANT(S)			APPLICANT YEH				
(Use several sheets if necessary)  Date Submitted to PTO: Octob r 20, 2003			FILING DATE Jun 24, 2003		GROUP <b>2812</b>		
U.S. PATENT DOCUMENTS							
ONITIAL E	DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE	
OCT 2 0 2003 🖁	4,330,363	05/18/82	Biegesen et al.				
	4,592,799	06/03/86	Hayafuji				
& TRADEMARK	5,021,119	06/04/91	Fan et al.				
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	6,495,405 B2	12/17/02	Voutsas et al.				
FOREIGN PATENT DOCUMENTS							
	DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUBCLASS	TRANSLATION YES/NO/ OR ABSTRACT	
OTHER DOCUMENT(S) (Including Author, Title, Date, Pertinent Pages, Etc.)							
	Recessed-Char	High-Performance Low-Temperature Poly-Si TFTs Crystallized by Excimer Laser with Recessed-Channel Structure, Lin et al., IEEE Electron Device Letters, Vol. 22, No. 6, June 2001, pages 269-271					
	Prepatterned La	Performance Improvement Obtained for Thin-Fil Transistors Fabricated in Prepatterned Laser-Recrystallized Polysilicon, Giust et al., IEEE Electron Device Letters, Vol. 18, No. 6, June 1997, pages 296-298					
	Comparison of on SiO₂, Giust o	Comparison of excimer laser recytstallized prepatterned and unpatterned silicon films on SiO <sub>2</sub> , Giust et al., J.Appl.Phys. 81(3), 1 February 1997, pages 1204-1211					
		High-Performance Single Crystalline-Silicon TFTs on a Non-Alkali Glass Substrate, Sano et al. Fujitsu Laboratories Ltd., Atsugi 243-0197, Japan (C) 2002 IEEE					
EXAMINER			DATE CONSIDER	RED	-		

<sup>\*</sup>EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.